

INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

ATTY DOCKET NO.
YOR920010565US2

SERIAL NO. 10/787,487
~~Not Yet Assigned~~

Clevenger et al.

FILING 08/26/04
Concurrently Herewith

GROUP 2822
Unknown

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
JmJ	5,903,493	05/11/1999	Lee			
	6,033,963	03/07/2000	Huang et al.			
	6,049,114	04/11/2000	Maiti et al.			
	6,057,583	05/02/2000	Gardner et al.			
	6,130,123	10/10/2000	Liang et al.			
	6,165,858	12/26/2000	Gardner et al.			
	6,198,617	03/06/2001	Sun			
	6,341,056	01/22/02	Allman et al.			
	6,451,667	09/17/02	Ning			
JmJ	6,528,834	03/04/03	Durcan et al.			

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
						YES	NO

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

JmJ	"New Paradigm of Silicon Technology," Tadahihiro Ohmi, et al., Proceedings of the IEEE, Vol. 89, No. 3, March 2001, pp. 394-412
JmJ	"Dual-Metal Gate CMOS Technology with Ultrathin Silicon Nitride Gate Dielectric," Yee-Chia Yeo et al., IEEE Electron Device Letters, Vol. 22, No. 5, May 2001, pp. 227-229

EXAMINER

T. M. Thomas

DATE CONSIDERED

06-24-05

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.



Substitute for form 1448A/PTO

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(use as many sheets as necessary)

Sheet 1

of

1

Complete If Known

Application Number	10/787,487
Filing Date	02/26/04
First Named Inventor	Clevenger et al.
Group Art Unit	2522 1822
Examiner Name	Not Yet Assigned T.M. Thomas
Attorney Docket Number	YOR920010565US2

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant/Inventor of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
JML		6,285,038		Rhodes	09/04/2001	
		6,033,983		Huang et al.	03/07/2000	

U.S. PATENT PUBLICATIONS

Examiner Initials*	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant/Inventor of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Number		Name of Patentee or Applicant/Inventor of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Office ³	Number				
JML			JP2001-144188		02/25/2001		

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T ²

Examiner
Signature

T.M. Thomas

Date
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06-24-05

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